

NDL7660P

1 310 nm OPTICAL CATV/ANALOG APPLICATIONS INGAASP MQW-DFB LASER DIODE MODULE

DESCRIPTION

NDL7660P is a 1 310 nm DFB (Distributed Feed-Back) laser diode, that has a newly developed Multiple Quantum Well (MQW) structure, butterfly package module with optical isolator. It is especially designed for a 6 mW light source of CATV analog applications.

FEATURES

Low noise RIN = -155 dB/Hz
 Low distortion CSO = -60 dBc
 CTB = -65 dBc

High output power
 Long wavelength
 Pf = 6.0 mW MIN.
 \(\rho_p = 1 310 \) nm

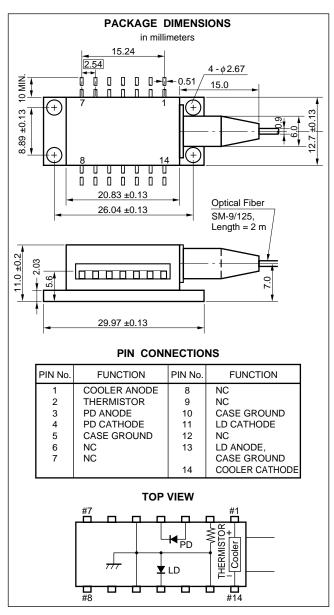
High isolation 40 dBInternal InGaAs monitor PD

· Internal thermoelectric cooler

- Hermetically sealed 14 pin butterfly package
- Singlemode fiber pigtail
- · Wide operating temperature range
- · High reliability

ORDERING INFORMATION

Part Number	Available Connector
NDL7660P	Without Connector
NDL7660PC	With FC-UPC Connector
NDL7660PD	With SC-UPC Connector





ABSOLUTE MAXIMUM RATINGS (Tc = 25 °C)

Parameter	Symbol	Ratings	Unit
Operating Case Temperature	Tc	−20 to +65	°C
Storage Temperature	T _{stg}	-40 to +70	°C
Lead Soldering Temperature (10 s)	T _{sld}	260	°C
Optical Output Power	Pf	15	mW
Forward Current of LD	lF	150	mA
Reverse Voltage of LD	VR	2.0	٧
Forward Current of PD	lF	10	mA
Reverse Voltage of PD	VR	20	V
Cooler Current	lc	1.0	Α
Cooler Voltage	Vc	2.0	V

ELECTRO-OPTICAL CHARACTERISTICS (TLD = 25 °C, Tc = -20 °C to +65 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Threshold Current	Ith			20	35	mA
Forward Voltage	VF	IF = 30 mA	0.9	1.2	1.4	V
Optical Output Power from Fiber (Recommended Operating Point)	P _{op} *1		6.0			mW
Spontaneous Emission Power from Fiber	Ps	lb = lth			50	μW
Differential Efficiency from Fiber	η d	$P_f \leq P_{op}$	0.16	0.22		W/A
Peak Emission Wavelength	λ_{P}	$P_f = P_{op}$	1 290	1 310	1 330	nm
Sub-mode Suppression Ratio	SMSR	$P_f = P_{op}$	30	35		dB
1 dB Bandwidth	f	$P_f = P_{op}$	900			MHz
Relative Intensity Noise	RIN*2	$P_f = P_{op}$		-155	-150	dB/Hz
Composite Second Order Distortion	CSO ^{*3}	$P_f = P_{op}$		-60	-55	dBc
Composite Triple Beat Distortion	CTB*3	$P_f = P_{op}$		-65	-60	dBc
Carrier to Noise Ratio	CNR ^{*3}	$P_f = P_{op}$	50			dBc
Isolation	ls		35	40		dB

*1. Recommended P_{op} value is supplied to each device.

*2. Conditions: $P_f = P_{op}$, CW

Measuring Bandwidth: 50 MHz to 600 MHz

Optical Reflection -40 dB

*3. Conditions: $P_f = P_{op}$, Optical Modulation Index = 3.5 %/channel

79 channel unmodulated carriers (55.25 MHz to 547.25 MHz)

Optical Reflection -40 dB, Optical Loss = 5.5 dB

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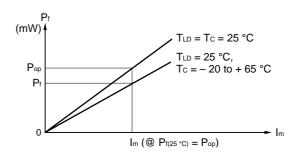
ELECTRO-OPTICAL CHARACTERISTICS

(Applicable to Monitor PD: T_{LD} = 25 °C, T_C = -20 °C to +65 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Monitor Current	Im	V _R = 5 V, P _f = P _{op}	50	200		μΑ
Dark Current	lσ	VR = 5 V		2	10	nA
Tracking Error	γ^{*4}	I _m = const.			0.5	dB

*4. Tracking Error : γ

$$\gamma = 10 \log \frac{P_f}{P_{op}}$$



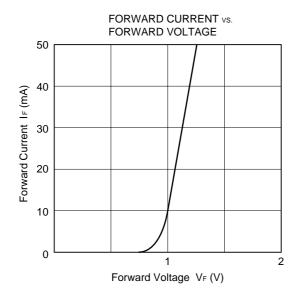
ELECTRO-OPTICAL CHARACTERISTICS

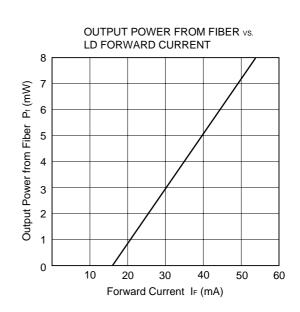
(Applicable to Thermistor and TE Cooler: TLD = 25 °C, Tc = -20 °C to +65 °C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Thermistor Resistance	R*5	TLD = 25 °C	9.5	10	10.5	kΩ
Cooler Current	lc	ΔT = 40 K		0.6	0.8	Α
Cooler Voltage	Vc	ΔT = 40 K		1.1	1.5	V
Cooling Capacity	∆T ^{*6}	Ic = 0.8 A, P _f = P _{op}	40			K

^{*5.} B Constant = $3400 \pm 100 \text{ K}$

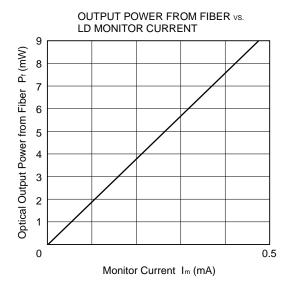
TYPICAL CHARACTERISTICS (Tc = 25 °C)

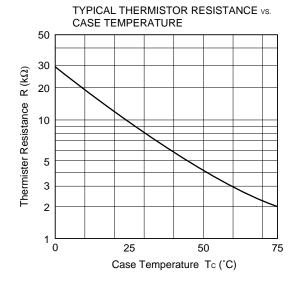


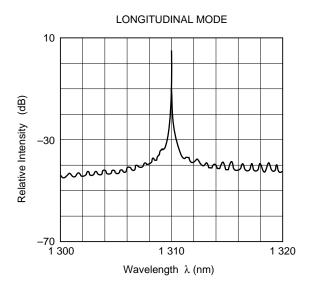


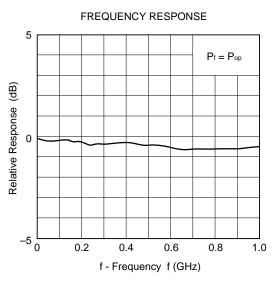
^{*6.} $\Delta T = |Tc - TLD|$

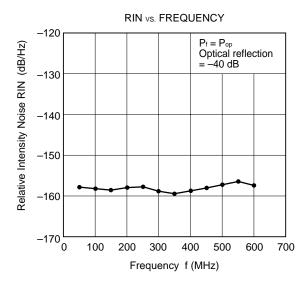














DFB LASER DIODE FAMILY FOR CATV/ANALOG APPLICATIONS

Features		Pop: (Operating poin	t power (min.	value)		Remarks
Packages	3 mW min.	4 mW min.	6 mW min.	8 mW min.	12 mW min.	15 mW min.	Remarks
14 pin BFY module with SMF	NDL7680P	NDL7650P	NDL7660P	NDL7670P	NDL7672P	NDL7673P	BFY module with monitor PD, TEC, thermistor, isolator

REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	LEI-1201
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E

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CAUTION

Within this module there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.



AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

NEC Corporation NEC Building, 7-1, Shiba 5-chome, Minato-ku, Tokyo 108-01, Japan
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Manufactured:
Serial Number:
This product conforms to FDA
regulations as applicable
to standards 21 CFR Chapter 1.
Subchapter J.

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

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Anti-radioactive design is not implemented in this product.

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